

Features

- Micropower operation
- Operation with North or South Pole
- 1.65 to 3.3V battery operation
- Chopper stabilized
 - Superior temperature stability
 - Extremely Low Switch-Point Drift
 - Insensitive to Physical Stress
- Good RF noise immunity
- -40°C to 85°C operating temperature
- ESD > 4KV in human body mode
- SOT553: Available in "Green" Molding Compound (No Br, Sb)
- Lead Free Finish/RoHS Compliant (Note 1)

General Description

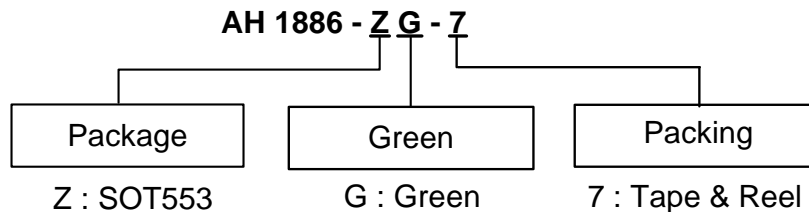
AH1886 is with two Hall effect plates and dual CMOS output driver, mainly designed for battery-powered, hand-held equipment (such as Cellular and Cordless Phone, PDA). The total operation power is down to 15uW in the 1.8V supply. Either north or south pole of sufficient strength will turn the output1 on. The output1 will be turned off under no magnetic field.


While the magnetic flux density (**B**) is larger than operate point (**Bop**), the output1 will be turned on (low), the output1 is held until **B** is lower than release point (**Brp**), then turned off.

Applications

- Cellular phone
- PDA
- Cordless phone

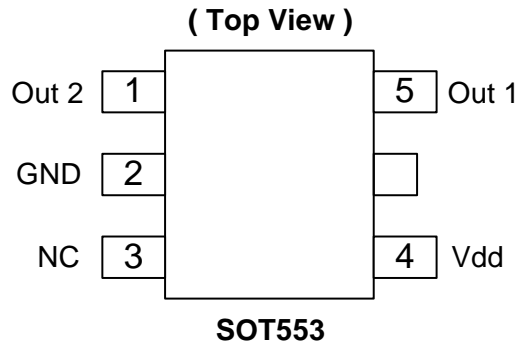
Ordering Information



Device	Package Code	Packaging (Note 2)	7" Tape and Reel	
			Quantity	Part Number Suffix
 AH1886-ZG-7	Z	SOT553	3000/Tape & Reel	-7

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied, see *EU Directive 2002/95/EC Annex Notes*.
 2. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

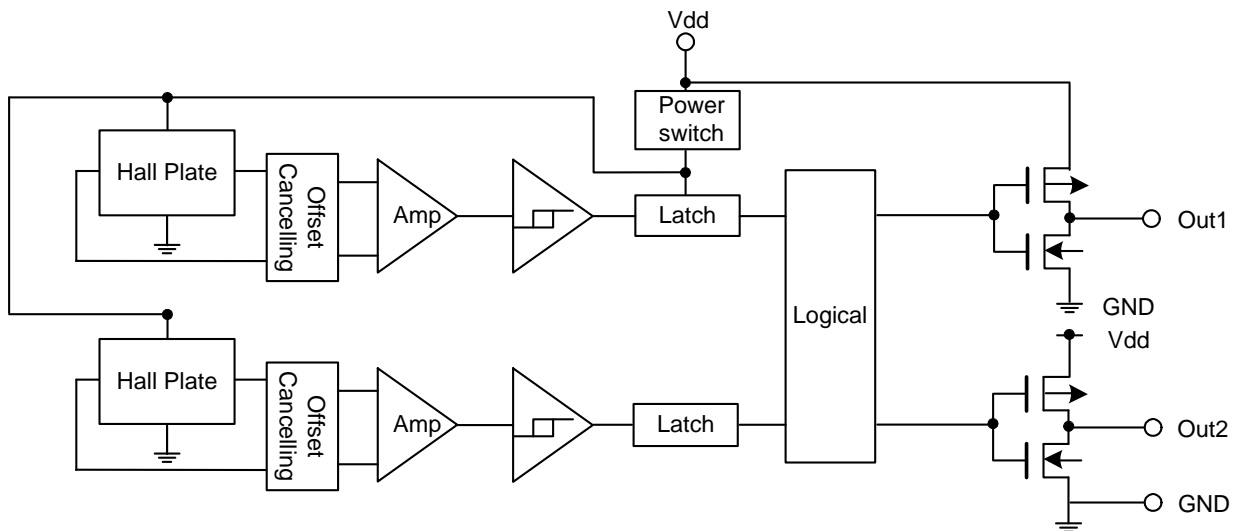
Pin Assignment



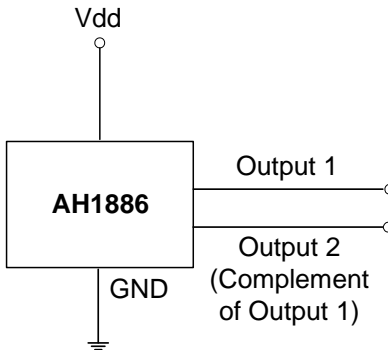
Pin Descriptions

Pin Name	P/I/O	Pin #	Description
Out 2	O	1	Output Pin (Complement of Out 1)
GND	P/I	2	Ground
NC		3	No Connection
Vdd	P/I	4	Power Supply Voltage
Out 1	O	5	Output Pin (active Low)

Block Diagram



Typical Circuit



Absolute Maximum Ratings (at TA = 25°C)

Symbol	Characteristics	Values	Unit
Vdd	Supply voltage	5	V
B	Magnetic flux density	Unlimited	
TA	Operating Temperature Range	-40 to +85	°C
Ts	Storage Temperature Range	-65 to +150	°C
PD	Package Power Dissipation	230	mW
TJ	Maximum Junction Temperature	150	°C

Recommended Operating Conditions (TA = 25°C)

Symbol	Parameter	Conditions	Rating	Unit
Vdd	Supply Voltage	Operating	1.65~3.3	V

Electrical Characteristics (TA = +25°C, Vdd = 1.8V; unless otherwise specified)

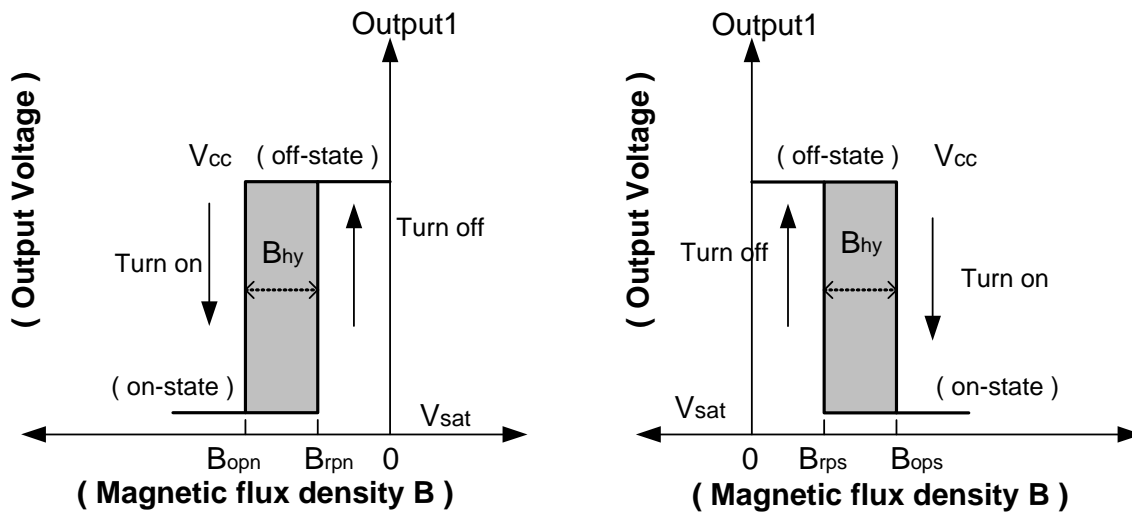
Symbol	Characteristic	Conditions	Min	Typ.	Max	Unit
V _{OH}	Output On Voltage (High side)	I _O = -0.5mA	V _{dd} -0.2	-	-	V
V _{OL}	Output On Voltage (Low side)	I _O = 0.5mA	-	-	0.2	V
I _{off}	Output Leakage Current	Output off	-	<0.1	1	μA
I _{dd(en)}	Supply Current	Chip enable	-	2	4	mA
I _{dd(dis)}		Chip disable	-	5	8	μA
I _{dd(avg)}		average supply current	-	7	12	μA
T _{awake}	Awake Time		-	50	100	μs
T _{period}	Period		-	50	100	ms
D.C.	Duty Cycle		-	0.1	-	%

Magnetic Characteristics (TA = 25°C, Vdd = 1.8V~3.0V) (Note 3)

(1mT=10 Gauss)

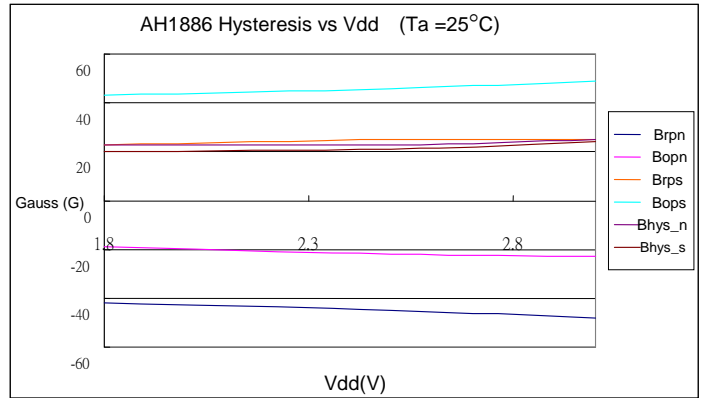
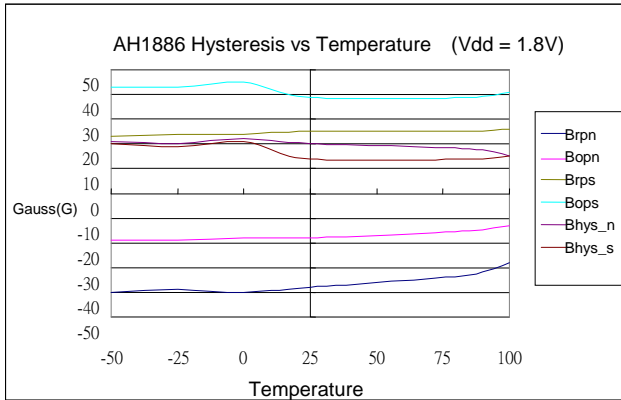
Symbol	Characteristic (Note 4)	Min	Typ.	Max	Unit
B _{ops} (south pole to brand side)	Operate Point	-	37	55	Gauss
B _{opn} (north pole to brand side)		-55	-37	-	
B _{rps} (south pole to brand side)	Release Point	6	29	-	
B _{rpn} (north pole to brand side)		-	-29	-6	
B _{hy} (B _{opx} - B _{rpx})	Hysteresis	3	8	-	

Notes: 3. Typical data is at Ta = 25°C, Vdd = 3V, and for design information only.
 4. Operate point and release point will vary with supply voltage and operating temperature.

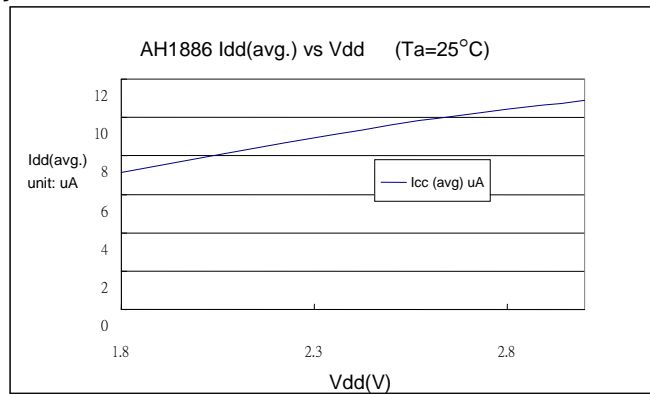
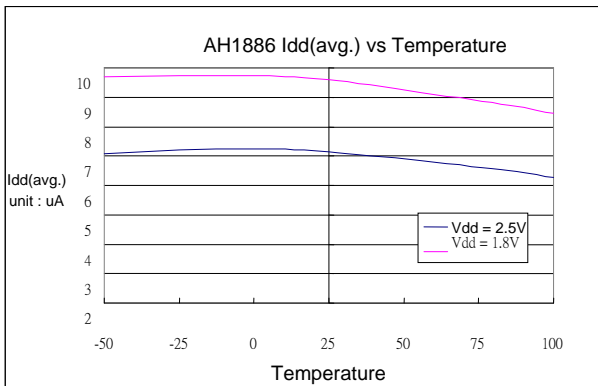


Typical Operating Characteristics

Switching Point

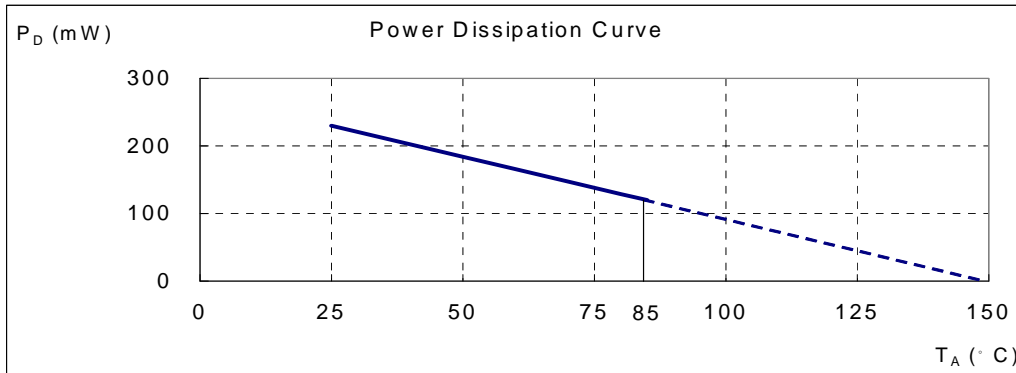


Supply Current



Performance Characteristics

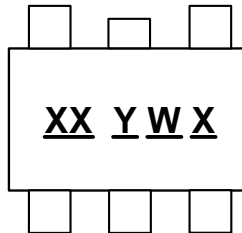
T _A (°C)	25	50	60	70	80	85	90	100	110	120	130	140	150
P _D (mW)	230	184	166	147	129	120	110	92	74	55	37	18	0



Marking Information

(1) SOT553

(Top View)



XX : Identification Code
Y : Year : 0~9
W : Week : A~Z : 1~26 week;
a~z : 27~52 week; z represents
52 and 53 week
X : A~Z : Green

Part Number	Package	Identification Code
AH1886	SOT553	KT

